QDLASER

QLF063A-4030T50

Preliminary

640 nm 30mW FP LASER TO-CAN, Anode common type, Tc=50de.C

C00125-01 January 2014



1. DESCRIPTION

The QLF063A-4030T50 is a 640 nm quantum well laser device designed for visible laser application. The laser diode is mounted into a TO-56 header including a monitor PD and hermetic sealed with a flat glass cap.

2. FEATURES

- 640 nm FP-LD
- Operating temperature range=-10 to 50deg.C
- Φ5.6mm TO-CAN package
- Including monitor PD
- Anode common type

3. APPLICATIONS

- Industrial laser markers
- Measuring instruments

4. ABSOLUTE MAXIMUM RATING

(CW operation, $T_c = 25$ °C, unless otherwise specified)

PARAMETER	SYMBOL	RATING	UNIT
Optical output power	P _o (CW)	50	mW
LD reverse voltage	V_{RLD}	2	V
PD reverse voltage	V_{RPD}	30	V
Operation temperature	T_{c}	-10 to 50	°C
Storage temperature	T_{stg}	-40 to 85	°C

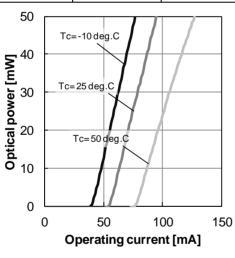


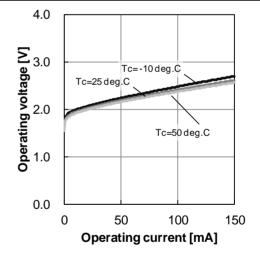
QLF063A-4030T50 C00125-01

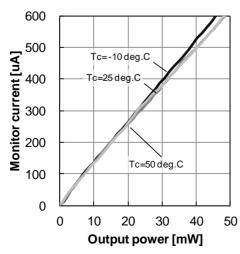
5. OPTICAL AND ELECTRICAL CHARACTERISTICS

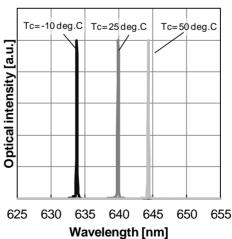
$(T_c = 25^{\circ}C, unless otherwise specified$
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			(1 _C - 2	25 C, ames	5 Other Wise	specifica)
PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Threshold current	I_{th}	CW	-	60	100	mA
Operation current	I _{op} (CW)	CW, P _o =30mW	-	90	140	mA
Operation voltage	V_{op}	CW, P _o =30mW	-	2.3	3.0	V
Slope efficiency	η	CW, P _o =5 - 30mW	0.8	1.0	-	W/A
Monitor current	I_{m}	CW , $P_o=30mW$, $V_{RD}=5 V$	-	300	-	μА
Peak wavelength	$\lambda_{ m p}$	CW, P _o =30mW	635	640	645	nm
Far filed pattern horizontal	θ_{h}	CW, P _o =30mW	6	9	13	deg.
Far filed pattern vertical	$\theta_{ m v}$	CW, P _o =30mW	13	17	22	deg.
Beam angle Horizontal	$d\theta_h$	CW, P _o =30 mW	-3	-	3	deg.
Beam angle vertical	$d\theta_{ m v}$	CW, P _o =30 mW	-3	-	3	deg.





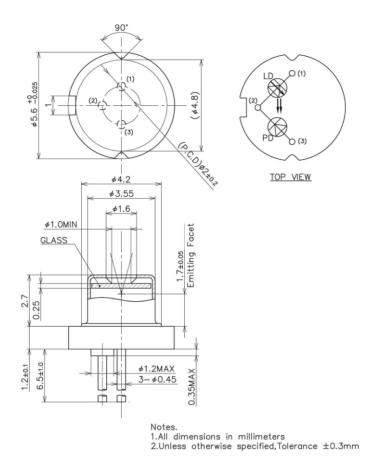






QLF063A-4030T50 C00125-01

6. Outline Drawing



Notice

Safety Information

This product is classified as Class 3B laser product, and complies with 21 CFR Part 1040.10. Please do not take a look laser lighting in operations since laser devices may cause troubles to human eyes. Please do not eat, burn, break and make chemical process of the products since they contain GaAs material.

Handling products

Semiconductor lasers are easily damaged by external stress such as excess temperature and ESD.

Please pay attention to handling products, and use within range of maximum ratings.

QD Laser takes no responsibility for any failure or unusual operation resulting from improper handling, or unusual physical or electrical stress.

RoHS

This product conforms to RoHS compliance related EU Directive 2002/95/EC.

QD Laser, Inc.

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